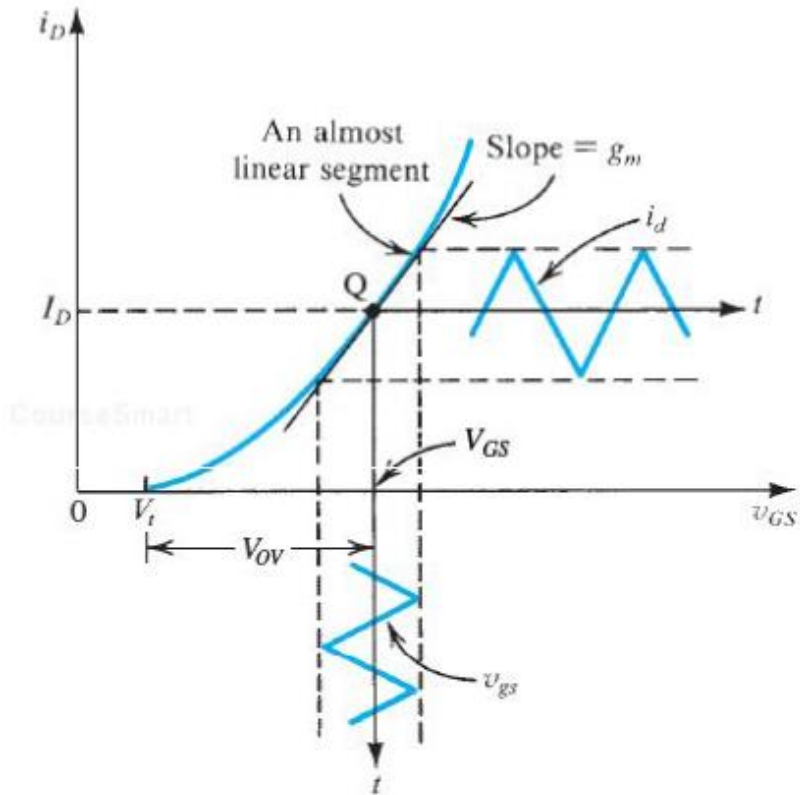
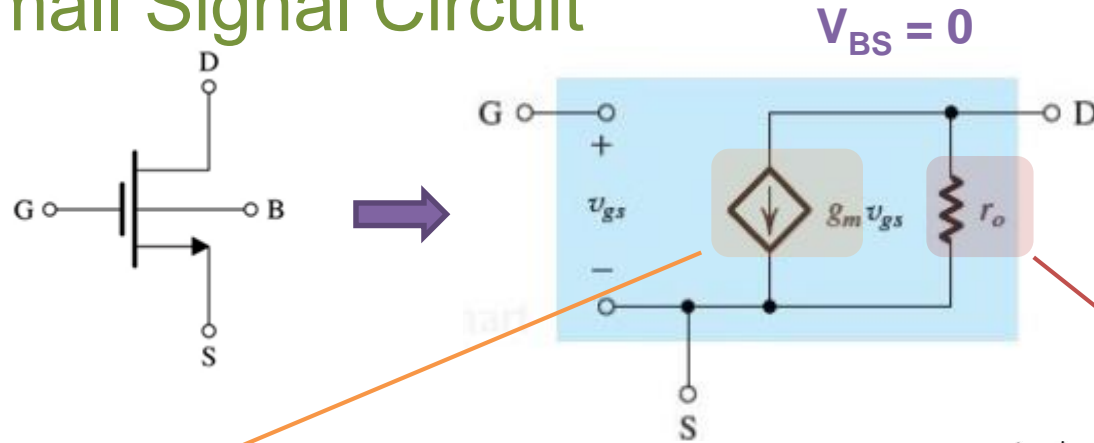


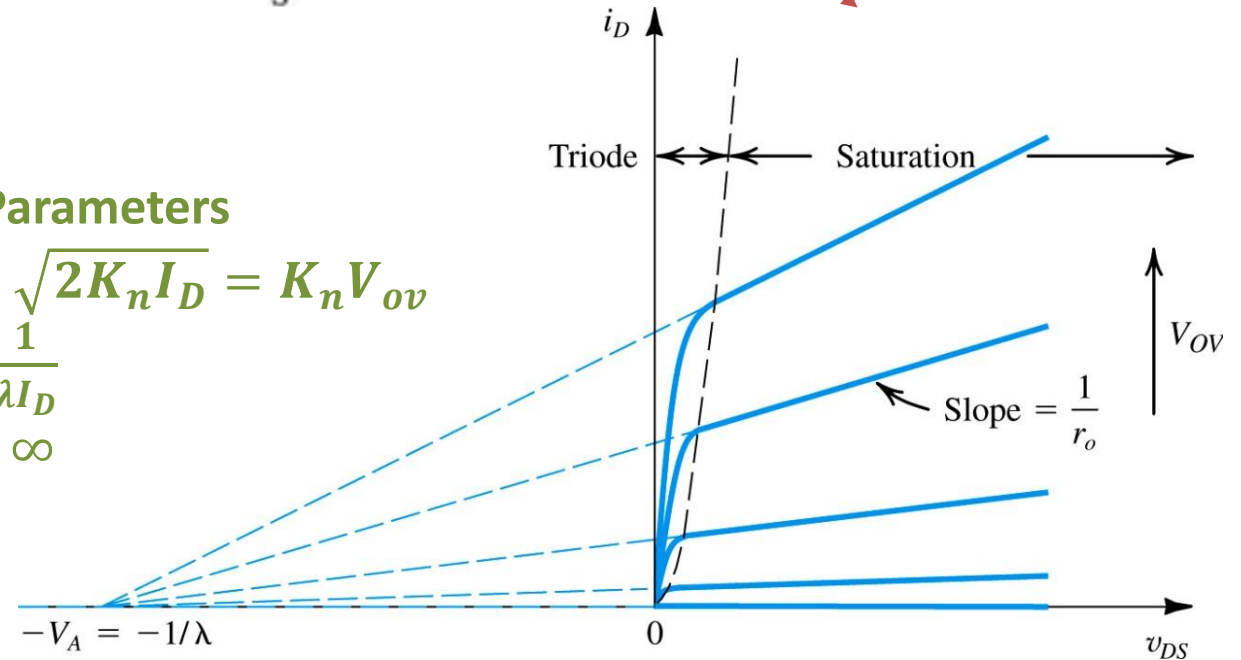
Last Lecture → MOS Small Signal Circuit

- Trans-conductance (g_m)
- Output Impedance (r_o)
- Input Impedance

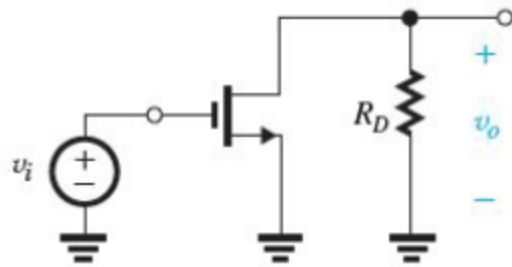


Small Signal Parameters

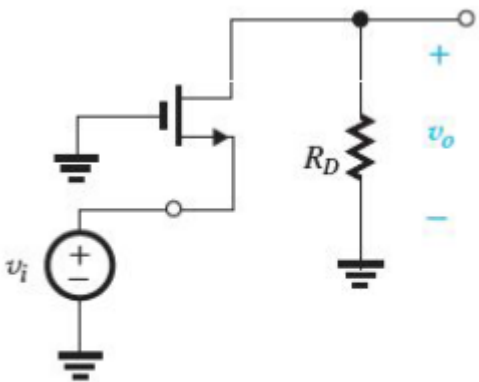
- $g_m = \sqrt{2K_n I_D} = K_n V_{ov}$
- $r_o = \frac{1}{\lambda I_D}$
- $r_{in} = \infty$



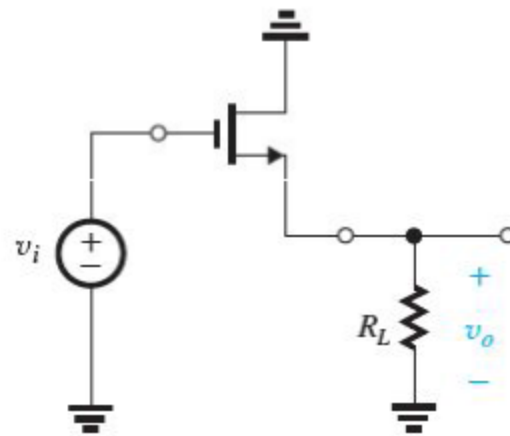
Basic MOSFETs Amplifier Configuration



(a) Common Source (CS)



(b) Common Gate (CG)

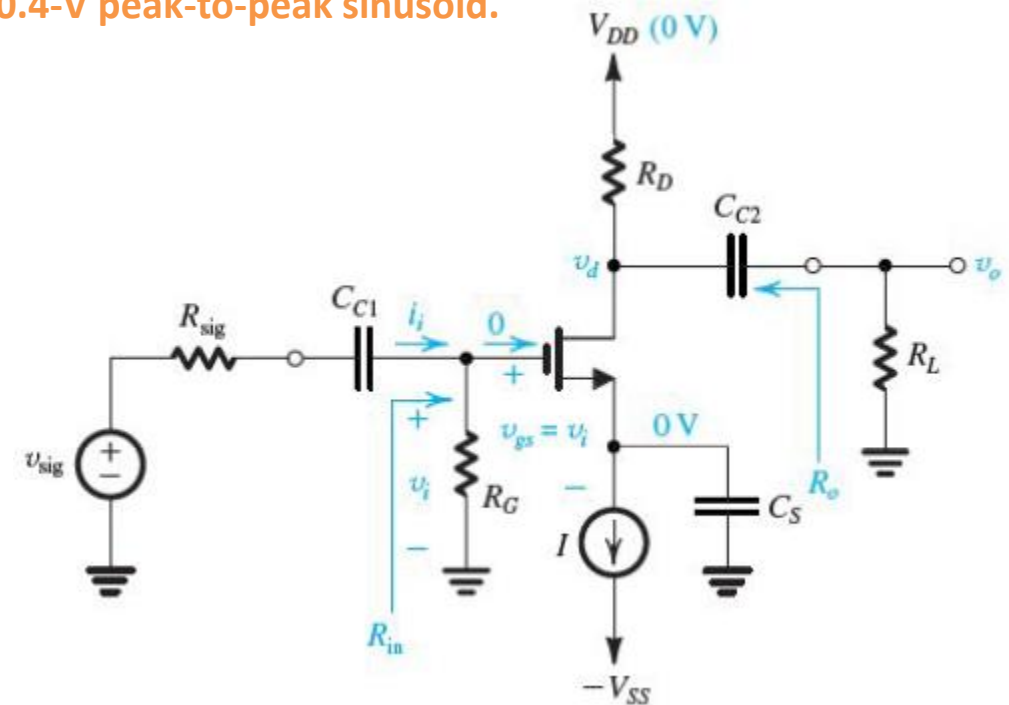


(c) Common Drain (CD)

Exercise 5.38

Consider the given common source amplifier with $g_m=1\text{mA/V}$, $r_o=150\text{k}\Omega$, $R_{sig}=100\text{k}\Omega$, and $R_L=15\text{k}\Omega$.

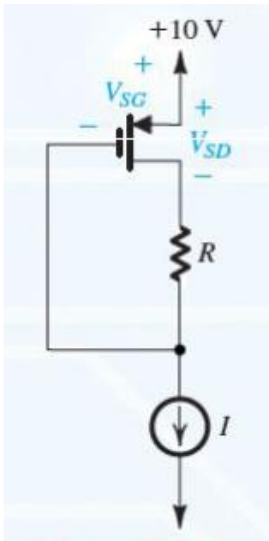
- Calculate R_{in} , $A_{v_cs}=V_o/V_i$, and R_o , both without and with r_o taken into account
- Calculate the overall voltage gain $G_v=v_o/v_{sig}$, with r_o taken into account
- Determine output signal v_o if v_{sig} is a 0.4-V peak-to-peak sinusoid.



Problem 5.58

For the PMOS transistor in the circuit shown below, assume $K_p=200\mu\text{A}/\text{V}^2$, and $|V_{tp}|=1\text{V}$.

- 1) For $I=100\mu\text{A}$, find the voltages V_{SD} and V_{SG} for $R=0$, $10\text{K}\Omega$, $30\text{K}\Omega$, and $100\text{k}\Omega$.
- 2) For what value of R is $V_{SD}=V_{SG}$? $V_{SD}=V_{SG}/2$? $V_{SD}=V_{SG}/10$?



Problem

In the circuit shown below, transistor Q_1 and Q_2 have $V_t=1V$, and the process trans-conductance parameter $k_n'=100\mu A/V^2$. Find V_1 , V_2 , and V_3 for each of the following cases:

- $(W/L)_1 = (W/L)_2 = 20$
- $(W/L)_1 = 1.5 \cdot (W/L)_2 = 20$

